- STMicroelectronics PREFERRED SALESTYPE
- HIGH VOLTAGE CAPABILITY ( > 1500 V )
- NPN TRANSISTOR WITH INTEGRATED FREEWHEELING DIODE
- FULLY INSULATED PACKAGE (U.L. COMPLIANT) FOR EASY MOUNTING


## APPLICATIONS:

- HORIZONTAL DEFLECTION FOR COLOUR TV UP TO 25"


## DESCRIPTION

The BU508DFI is manufactured using Multiepitaxial Mesa technology for cost-effective high performance and uses a Hollow Emitter structure to enhance switching speeds.


INTERNAL SCHEMATIC DIAGRAM


## ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
| :---: | :--- | :---: | :---: |
| $\mathrm{V}_{\mathrm{CES}}$ | Collector-Emitter Voltage $\left(\mathrm{V}_{\mathrm{BE}}=0\right)$ | 1500 | V |
| $\mathrm{~V}_{\mathrm{CEO}}$ | Collector-Emitter Voltage $\left(\mathrm{I}_{\mathrm{B}}=0\right)$ | 700 | V |
| $\mathrm{~V}_{\text {EBO }}$ | Emitter-Base Voltage $\left(\mathrm{I}_{\mathrm{C}}=0\right)$ | 10 | V |
| $\mathrm{I}_{\mathrm{C}}$ | Collector Current | 8 | A |
| $\mathrm{I}_{\mathrm{CM}}$ | Collector Peak Current $\left(\mathrm{t}_{\mathrm{p}}<5 \mathrm{~ms}\right)$ | 15 | A |
| $\mathrm{I}_{\mathrm{B}}$ | Base Current | 5 | A |
| $\mathrm{I}_{\mathrm{BM}}$ | Base Peak Current $\left(\mathrm{t}_{\mathrm{p}}<5 \mathrm{~ms}\right)$ | 8 | A |
| $\mathrm{P}_{\text {tot }}$ | Total Dissipation at $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 50 | W |
| $\mathrm{~V}_{\text {isol }}$ | Insulation Withstand Voltage (RMS $)$ from All <br> Three Leads to Exernal Heatsink | 2500 | V |
| $\mathrm{~T}_{\text {stg }}$ | Storage Temperature | -65 to 150 | 150 |
| $\mathrm{~T}_{\mathrm{j}}$ | Max. Operating Junction Temperature | ${ }^{\circ} \mathrm{C}$ |  |

## BU508DFI

THERMAL DATA

| $R_{\text {thj-case }}$ | Thermal Resistance Junction-case | Max | 2.5 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| :--- | :--- | :--- | :--- | :--- |

ELECTRICAL CHARACTERISTICS ( $\mathrm{T}_{\text {case }}=25^{\circ} \mathrm{C}$ unless otherwise specified)

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Ices | Collector Cut-off Current ( $\mathrm{V}_{\mathrm{be}}=0$ ) | $\begin{array}{ll} \hline \mathrm{V}_{C E}=1500 \mathrm{~V} & \\ \mathrm{~V}_{\mathrm{CE}}=1500 \mathrm{~V} & \mathrm{~T}_{\mathrm{j}}=125^{\circ} \mathrm{C} \\ \hline \end{array}$ |  |  | $\begin{aligned} & 1 \\ & 2 \end{aligned}$ | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \end{aligned}$ |
| $I_{\text {ebo }}$ | Emitter Cut-off Current ( $\mathrm{IC}_{\mathrm{C}}=0$ ) | $\mathrm{V}_{\text {EB }}=5 \mathrm{~V}$ |  |  | 300 | mA |
| $\mathrm{V}_{\text {CEO(sus)* }}$ | Collector-Emitter Sustaining Voltage ( $\mathrm{IB}_{\mathrm{B}}=0$ ) | $\mathrm{IC}=100 \mathrm{~mA}$ | 700 |  |  | V |
| $\mathrm{V}_{\text {CE(sat)* }}$ | Collector-Emitter <br> Saturation Voltage | $\mathrm{I}_{\mathrm{C}}=4.5 \mathrm{~A} \quad \mathrm{I}_{\mathrm{B}}=2 \mathrm{~A}$ |  |  | 1 | V |
| $\mathrm{V}_{\mathrm{BE} \text { (sat)* }}$ | Base-Emitter <br> Saturation Voltage | $\mathrm{I}_{\mathrm{C}}=4.5 \mathrm{~A} \quad \mathrm{I}_{\mathrm{B}}=2 \mathrm{~A}$ |  |  | 1.3 | V |
| $\begin{aligned} & \mathrm{t}_{\mathrm{s}} \\ & \mathrm{t}_{\mathrm{f}} \end{aligned}$ | INDUCTIVE LOAD <br> Storage Time <br> Fall Time | $\begin{aligned} & \mathrm{I}_{\mathrm{C}}=4.5 \mathrm{~A} \quad \mathrm{~h}_{\mathrm{FE}}=2.5 \quad \mathrm{~V}_{\mathrm{CC}}=140 \mathrm{~V} \\ & \mathrm{~L}_{\mathrm{C}}=0.9 \mathrm{mH} \quad \mathrm{~L}_{\mathrm{B}}=3 \mu \mathrm{H} \\ & \text { (see figure 1) } \end{aligned}$ |  | $\begin{gathered} 7 \\ 550 \end{gathered}$ |  | $\mu \mathrm{S}$ ns |
| $\mathrm{V}_{\mathrm{F}}$ | Diode Forward Voltage | $\mathrm{I}_{\mathrm{F}}=4 \mathrm{~A}$ |  |  | 2 | V |
| ${ }_{\text {f }}$ | Transition Frequency | $\mathrm{IC}=0.1 \mathrm{~A} \quad \mathrm{~V}_{\mathrm{CE}}=5 \mathrm{~V} \quad \mathrm{f}=5 \mathrm{MHz}$ |  | 7 |  | MHz |

* Pulsed: Pulse duration $=300 \mu \mathrm{~s}$, duty cycle 1.5 \%

Safe Operating Area


Thermal Impedance


Derating Curve


Collector Emitter Saturation Voltage


Switching Time Inductive Load


DC Current Gain


Base Emitter Saturation Voltage


Switching Time Inductive Load


## BU508DFI

Switching Time Percentance vs. Case


Figure 1: Inductive Load Switching Test Circuit.


| DIM. | mm |  |  | inch |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | 5.35 |  | 5.65 | 0.211 |  | 0.222 |
| C | 3.30 |  | 3.80 | 0.130 |  | 0.150 |
| D | 2.90 |  | 3.10 | 0.114 |  | 0.122 |
| D1 | 1.88 |  | 2.08 | 0.074 |  | 0.082 |
| E | 0.75 |  | 0.95 | 0.030 |  | 0.037 |
| F | 1.05 |  | 1.25 | 0.041 |  | 0.049 |
| F2 | 1.50 |  | 1.70 | 0.059 |  | 0.067 |
| F3 | 1.90 |  | 2.10 | 0.075 |  | 0.083 |
| G | 10.80 |  | 11.20 | 0.425 |  | 0.441 |
| H | 15.80 |  | 16.20 | 0.622 |  | 0.638 |
| L |  |  |  |  | 0.354 |  |
| L1 | 20.80 |  | 21.20 | 0.819 |  | 0.835 |
| L2 | 19.10 |  | 19.90 | 0.752 |  | 0.783 |
| L3 | 22.80 |  | 23.60 | 0.898 |  | 0.929 |
| L4 | 40.50 |  | 42.50 | 1.594 |  | 1.673 |
| L5 | 4.85 |  | 5.25 | 0.191 |  | 0.207 |
| L6 | 20.25 |  | 20.75 | 0.797 |  | 0.817 |
| N | 2.1 |  | 2.3 | 0.083 |  | 0.091 |
| R |  |  |  |  | 0.181 |  |
| DIA | 3.5 |  |  | 3.7 | 0.138 |  |



## BU508DFI

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